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Volume 34 Number 11 November 2013

SEMICONDUCTOR PHYSICS
AC-electronic and dielectric properties of semiconducting phthalocyanine compounds: a comparativ

study (6 pages)
Safa'a M. Hraibat, Rushdi M-L. Kitaneh, Mohammad M. Abu-Samreh, and Abdelkarim M. Saleh

112002 Influence of an anisotropic parabolic potential on the quantum dot qubit (4 pages)

Zhao Cuilan, Cai Chunyu, and Xiao Jinglin

112003 Influence of incident angle on the defect mode of locally doped photonic crystal (4 pages)

Wang Jin, Wen Tingdun, Xu Liping, and Liu Zufan

SEMICONDUCTOR MATERIALS

113001 Correlation between electrical conductivity-optical band gap energy and precursor molarities ultrasonic spray deposition of ZnO thin films (5 pages)

Said Benramache, Okba Belahssen, Abderrazak Guettaf, and Ali Arif

113002 The growth and characterization of GaN films on cone-shaped patterned sapphire by MOCVD (5 pages)
Jing Liang, Xiao Hongling, Wang Xiaoliang, Wang Cuimei, Deng Qingwen, Li Zhidong, Ding Jieqin,
Wang Zhanguo, and Hou Xun

SEMICONDUCTOR DEVICES

114001 Modeling and simulation of centroid and inversion charge density in cylindrical surrounding gate MOSFETs including quantum effects (6 pages)

P. Vimala and N. B. Balamurugan

114002 A new approach to extracting the RF parameters of asymmetric DG MOSFETs with the NQS effect (5 pages)

Sudhansu Kumar Pati, Kalyan Koley, Arka Dutta, N Mohankumar, and Chandan Kumar Sarkar

RF and microwave characteristics of a 10 nm thick InGaN-channel gate recessed HEMT (6 pages)

T. R. Lenka, G. N. Dash, and A. K. Panda

114004 Low ohmic contact AlN/GaN HEMTs grown by MOCVD (3 pages)

Gu Guodong, Dun Shaobo, Lü Yuanjie, Han Tingting, Xu Peng, Yin Jiayun, and Feng Zhihong

114005 Improved memory performance of metal-oxide-nitride-oxide-silicon by annealing the SiO₂ tunnel layer in different nitridation atmospheres (4 pages)

He Meilin, Xu Jingping, Chen Jianxiong, and Liu Lu

114006 Light-extraction enhancement of freestanding GaN-based flip-chip light-emitting diodes using two-step roughening methods (4 pages)

An Tielei, Sun Bo, Wei Tongbo, Zhao Lixia, Duan Ruifei, Liao Yuanxun, Li Jinmin, and Yi Futing

114007 Effect of low temperature annealing on the electrical properties of an MOS capacitor with a HfO₂ dielectric and a TiN metal gate (4 pages)

Han Kai, Ma Xueli, Xiang Jinjuan, Yang Hong and Wang Wenwu

114008	The corner rounding modeling technique in SPICE simulations for deeply scaled MOSFETs (4 pages) Sun Wei and Yang Dake
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114013	The fabrication of vibration energy harvester arrays based on AlN piezoelectric film (4 pages) Shang Zhengguo, Li Dongling, Wen Zhiyu, and Zhao Xingqiang
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	SEMICONDUCTOR INTEGRATED CIRCUITS
115001	A digital input class-D audio amplifier with sixth-order PWM (6 pages) Luo Shumeng and Li Dongmei
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115005	A 97 dB dynamic range CSA-based readout circuit with analog temperature compensation for MEMS capacitive sensors (8 pages) Yin Tao, Zhang Chong, Wu Huanming, Wu Qisong, and Yang Haigang
115006	60-GHz array antenna with standard CMOS technology on Schott Borofloat (4 pages) Luo Jun, Wang Yan, and Yue Ruifeng
115007	A 4 GHz 32 bit direct digital frequency synthesizer based on a novel architecture (6 pages) Wu Jin, Chen Jianwu, Wu Danyu, Zhou Lei, Jiang Fan, Jin Zhi, and Liu Xinyu